

Small switching (60V, 2A)

2SK2463

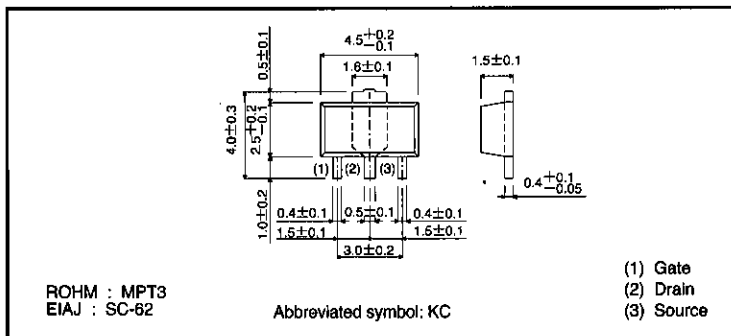
●Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide SOA (safe operating area).
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

●Structure

Silicon N-channel
MOSFET transistor

●External dimensions (Units: mm)



MOS FET

●Absolute maximum ratings (Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|-------------------------|-------------------|---------------------|------|
| Drain-source voltage | V _{DSS} | 60 | V |
| Gate-source voltage | V _{GSS} | ±20 | V |
| Drain current | Continuous | I _D | 2 |
| | Pulsed | I _{DP} *1 | 8 |
| Drain reverse current | Continuous | I _{DR} | 2 |
| | Pulsed | I _{DRP} *1 | 8 |
| Total power dissipation | P _D *2 | 2 | W |
| Channel temperature | T _{ch} | 150 | °C |
| Storage temperature | T _{stg} | -55~150 | °C |

*1 P_w ≤ 10 μs, Duty cycle ≤ 1% *2 When mounted on a 40 x 40 x 0.7 mm aluminum-ceramic board.

●Packaging specifications

| Type | Package | Bulk |
|---------|------------------------------|------|
| | Code | T100 |
| | Basic ordering unit (pieces) | 3000 |
| 2SK2463 | | ○ |

●Electrical characteristics (Ta = 25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|----------------------------------|----------------------|------|------|------|------|--|
| Gate leakage current | I _{gss} | — | — | ±100 | nA | V _{GS} =±20V, V _{DS} =0V |
| Drain-source breakdown voltage | V _{(BR)DSS} | 60 | — | — | V | I _D =1mA, V _{GS} =0V |
| Drain cutoff current | I _{DSS} | — | — | 10 | μA | V _{DS} =60V, V _{GS} =0V |
| Gate threshold voltage | V _{GS(th)} | 1 | — | 2.5 | V | V _{DS} =10V, I _D =1mA |
| Drain-source on-state resistance | R _{DS(on)} | — | 0.30 | 0.38 | Ω | I _D =1A, V _{GS} =10V |
| | | — | 0.45 | 0.58 | | I _D =1A, V _{GS} =4V |
| Forward propagation admittance | Y _{fs} * | 1.2 | — | — | S | V _{DS} =10V, I _D =1A |
| Input capacitance | C _{iss} | — | 200 | — | pF | V _{DS} =10V |
| Output capacitance | C _{oss} | — | 80 | — | pF | V _{GS} =0V |
| Reverse transfer capacitance | C _{rss} | — | 50 | — | pF | f=1MHz |
| Turn-on delay time | t _{d(on)} | — | 10 | — | ns | I _D =1A, V _{DD} ≐30V |
| Rise time | t _r | — | 25 | — | ns | V _{GS} =10V |
| Turn-off delay time | t _{d(off)} | — | 50 | — | ns | R _L =30Ω |
| Fall time | t _f | — | 50 | — | ns | R _G =10Ω |
| Reverse recovery time | t _{rr} | — | 70 | — | ns | I _{DR} =2A, V _{GS} =0V, di/dt=50A/μs |

* Pw≤300 μs, Duty cycle≤1%

●Electrical characteristic curves

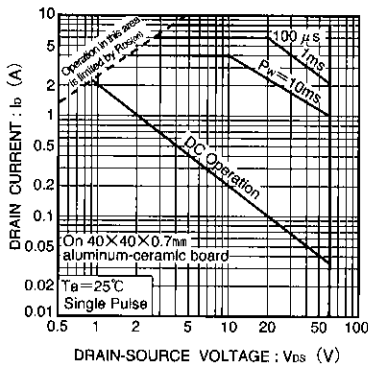


Fig.1 Maximum Safe Operating Area

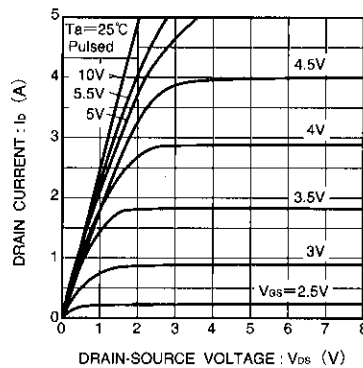


Fig.2 Typical Output Characteristics

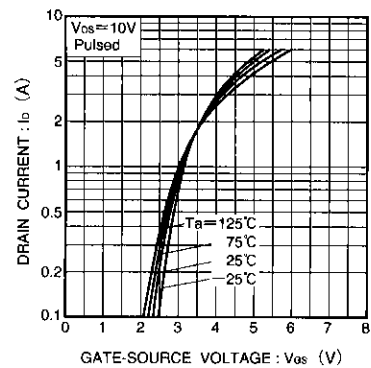


Fig.3 Typical Transfer Characteristics

●Electrical characteristic curves

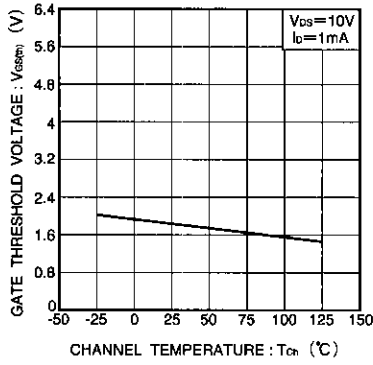


Fig.4 Gate Threshold Voltage vs. Channel Temperature

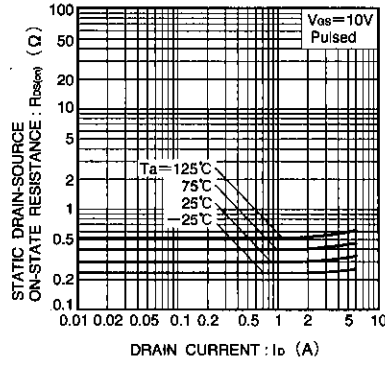


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current (I)

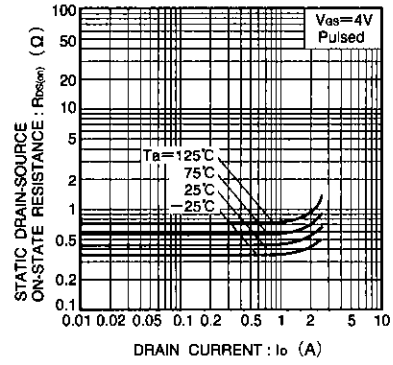


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current (II)

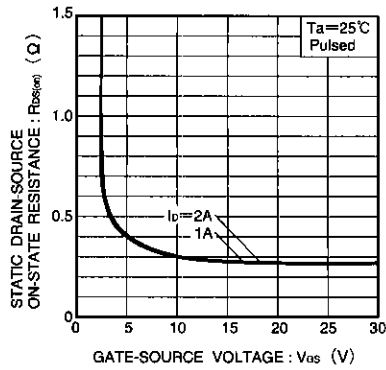


Fig.7 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

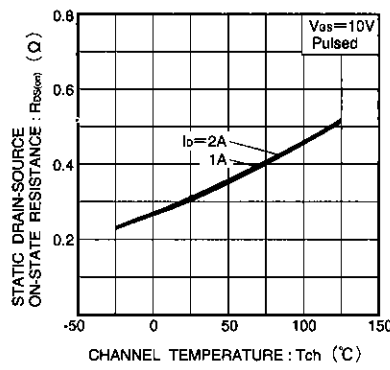


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

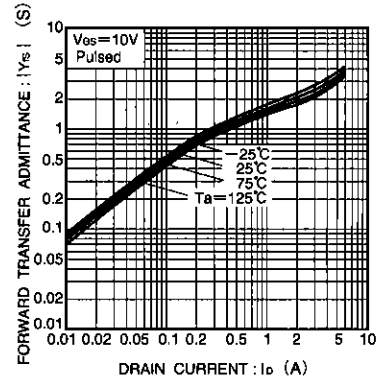


Fig.9 Forward Transfer Admittance vs. Drain Current

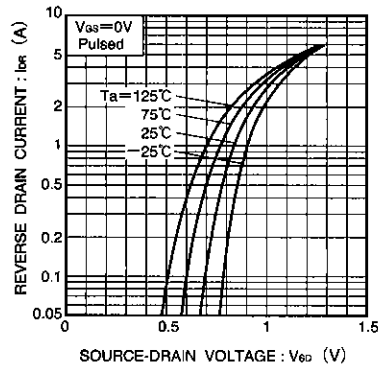


Fig.10 Reverse Drain Current vs. Source-Drain Voltage (I)

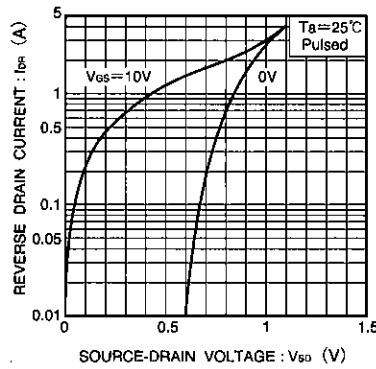


Fig.11 Reverse Drain Current vs. Source-Drain Voltage (II)

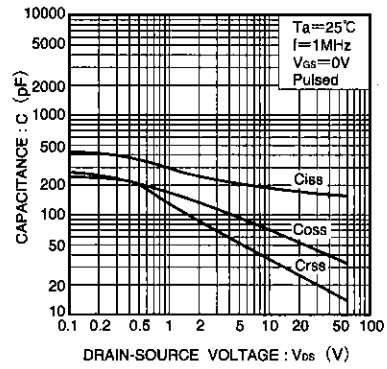


Fig.12 Typical Capacitance vs. Drain-Source Voltage

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●Electrical characteristic curves

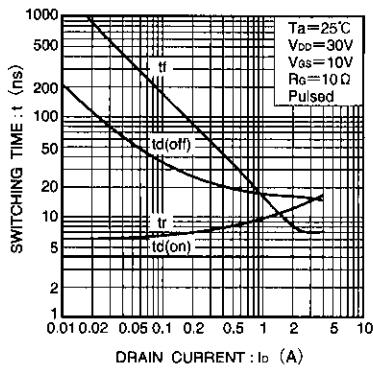


Fig.13 Switching Characteristics
(See Figure. 16 and 17 for measurement circuits)

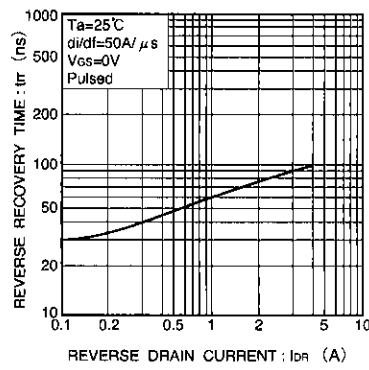


Fig.14 Reverse Recovery Time vs. Reverse Drain Current

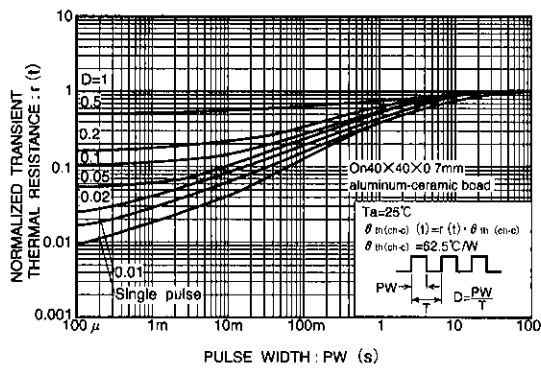


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

●Switching characteristics measurement circuit

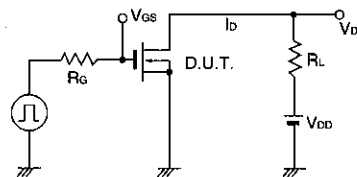


Fig.16 Switching Time Measurement Circuit

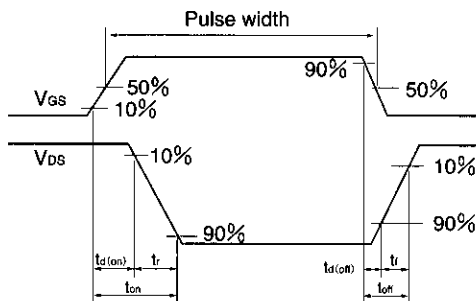


Fig.17 Switching Time Waveforms

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